

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

MCH6124 — PNP Epitaxial Planar Silicon Transistor Load Switch Applications

Applications

· Load switch, DC-DC converter, motor drivers, charger

Features

- · Adoption of MBIT process
- · Low collector-to-emitter saturation voltage
- · Large current capacity
- · High speed switching
- Ultrasmall-sized package permitting applied sets to be made small and slim (0.85mm)
- · High allowable power dissipation
- · IECO is guaranteed for preventing reverse flow from the collector to the emitter

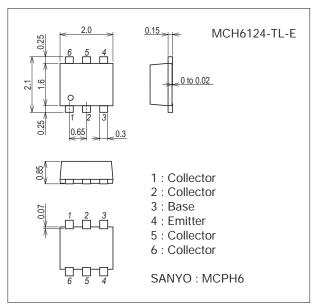
Specifications

Absolute Maximum Ratings at Ta=25°C

	3			
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-20	V
Collector-to-Emitter Voltage	VCEO		-20	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	IC		-3	А
Collector Current (Pulse)	ICP		-5	Α
Base Current	ΙΒ		-600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm)	1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7022A-007



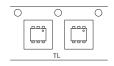
Product & Package Information

• Package : MCPH6

• JEITA, JEDEC : SC-88, SC-70-6, SOT-363

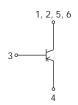
• Minimum Packing Quantity : 3,000 pcs./reel

Packing Type : TL Marking





Electrical Connection



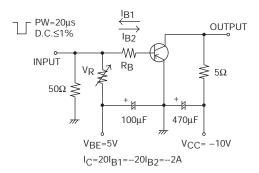
SANYO Semiconductor Co., Ltd.

http://www.sanyosemi.com/en/network/

Electrical Characteristics at Ta=25°C

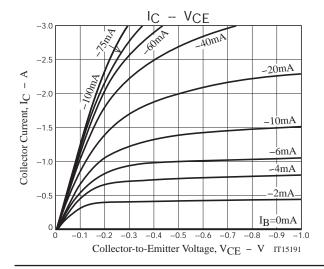
Parameter	Symbol	Conditions	Ratings			Linit	
Parameter	Syllibol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} = -20V, I _E =0A			-0.1	μΑ	
Emitter Cutoff Current	IEBO	V _{EB} = -4V, I _C =0A			-0.1	μΑ	
Emitter Cutoff Current	IECO	V _{EC} = -4.5V, I _B =0A			-1	μΑ	
DC Current Gain	hFE	V _{CE} = -2V, I _C = -100mA	200		560		
Gain-Bandwidth Product	fŢ	V _{CE} = -10V, I _C = -300mA		400		MHz	
Output Capacitance	Cob	V _{CB} = -10V, f=1MHz		22		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = -1.5A, I _B = -75mA		-130	-195	mV	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = -1.5A, I _B = -75mA		-0.93	-1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC= -10μA, IE=0A	-20			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-20			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E = -10μA, I _C =0A	-5			V	
Turn-On Time	ton			35		ns	
Storage Time	t _{stg}	See specified Test Circuit.		65		ns	
Fall Time	tf			12		ns	

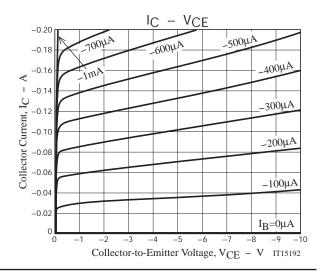
Switching Time Test Circuit

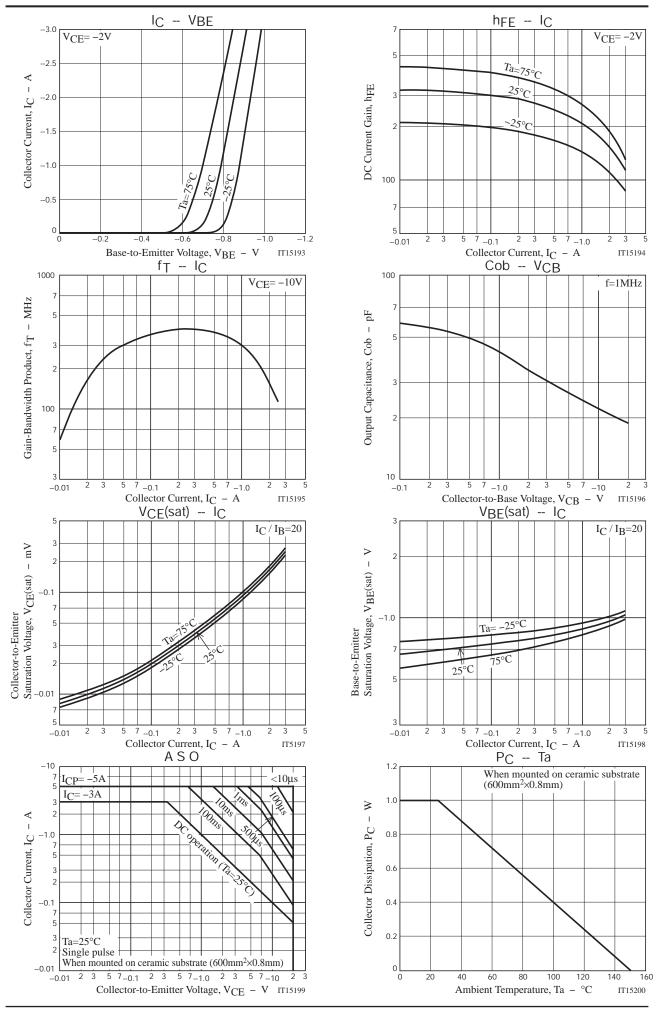


Ordering Information

Device	Package	Shipping	memo	
MCH6124-TL-E	МСРН6	3,000pcs./reel	Pb Free	





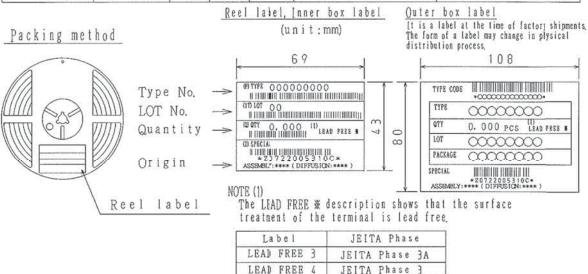


Embossed Taping Specification

MCH6124-TL-E

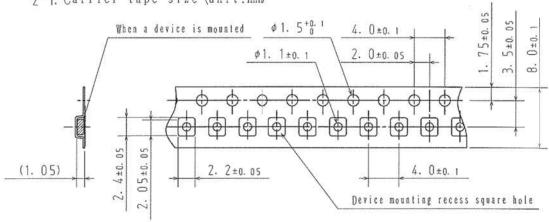
1. Packing Format

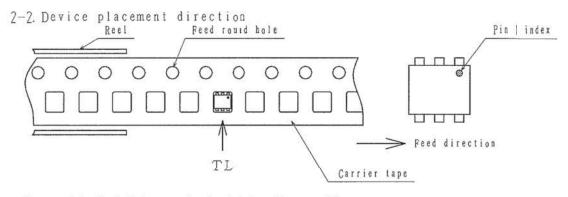
Package Name Car	Carrier Tape	Maximum Number of devices contained (yes)			Packing format		
	Туре	Reel	[nner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
MCPH6	MCP4	3, 000	15, 000	90, 000		6 inner boxes contained Dimensions:mm(external)	
					183×72×185	440×195×210	



2. Taping configuration

2-1. Carrier tape size (unit:mm)

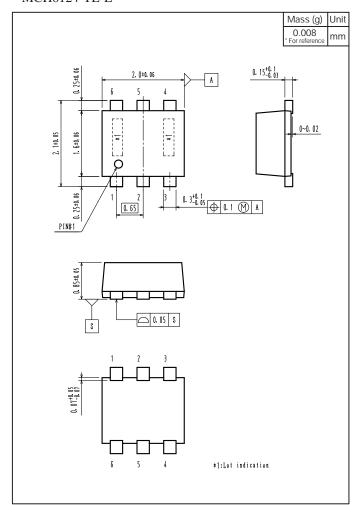




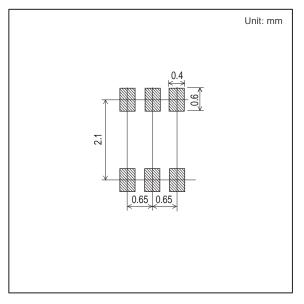
Those with pin 1 index on the feed hole side ·····TL

Outline Drawing

MCH6124-TL-E



Land Pattern Example



- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc., please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of November, 2012. Specifications and information herein are subject to change without notice.